

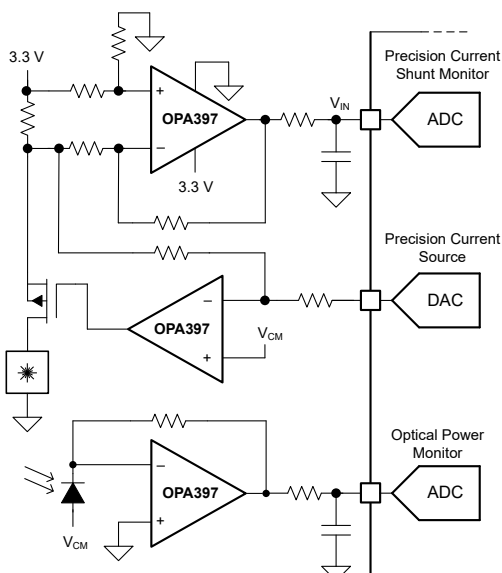
# OPAx397 Precision, Low-Offset-Voltage, Low-Noise, Low-Input-Bias-Current, Rail-to-Rail I/O, e-trim™ Operational Amplifiers

## 1 Features

- Low offset voltage:  $\pm 60 \mu\text{V}$  (maximum)
- Low-drift:  $\pm 0.18 \mu\text{V}/^\circ\text{C}$
- Low input bias current: 10 fA
- Low noise:  $4.4 \text{ nV}/\sqrt{\text{Hz}}$  at 10 kHz
- Low 1/f noise:  $2 \mu\text{V}_{\text{PP}}$  (0.1 Hz to 10 Hz)
- Low supply voltage operation: 1.7 V to 5.5 V
- Low quiescent current: 1.22 mA
- Fast settling:  $0.75 \mu\text{s}$  (1 V to 0.1%)
- Fast slew rate: 4.5 V/ $\mu\text{s}$
- High output current: +65/-55 mA short circuit
- Gain bandwidth: 13 MHz
- Rail-to-rail input and output
- Specified temperature range:  $-40^\circ\text{C}$  to  $+125^\circ\text{C}$
- EMI/RFI filtered inputs

## 2 Applications

- [Multiparameter patient monitor](#)
- [Electrocardiogram \(ECG\)](#)
- [Chemistry/gas analyzer](#)
- [Optical module](#)
- [Analog input module](#)
- [Process analytics \(pH, gas, concentration, force and humidity\)](#)
- [Gas detector](#)
- [Analog security camera](#)
- [Merchant DC/DC](#)
- [Pulse oximeter](#)
- [Inter-DC interconnect \(long-haul, submarine\)](#)
- [Data acquisition \(DAQ\)](#)



## OPAx397 Applications in Optical Modules

## 3 Description

The OPAx397 family of operational amplifiers (OPA397, OPA2397, and OPA4397) features ultra-low offset, offset drift, and input bias current with rail-to-rail input and output operation. In addition to precision dc accuracy, the ac performance is optimized for low noise and fast-settling transient response. These features make the OPAx397 an excellent choice for driving high-precision analog-to-digital converters (ADCs) or buffering the output of high-resolution, digital-to-analog converters (DACs).

The OPAx397 feature TI's e-trim™ operational amplifier technology to achieve ultra-low offset voltage and offset voltage drift without any input chopping or auto-zero techniques. This technique enables ultra-low input bias current for sensor inputs or photodiode current-to-voltage measurements, creating high-performance transimpedance stages for optical modules or medical instrumentation.

### Device Information

PART NUMBER	PACKAGE <sup>(1)</sup>	BODY SIZE (NOM)
OPA397	DSBGA (6) <sup>(3)</sup>	1.00 mm x 0.8 mm
	SC-70 (5) <sup>(3)</sup>	2.00 mm x 1.25 mm
	SOT-23 (5)	2.90 mm x 1.60 mm
OPA2397 <sup>(2)</sup>	DSBGA (9) <sup>(3)</sup>	1.20 mm x 1.20 mm
	VSSOP (8) <sup>(3)</sup>	3.00 mm x 3.00 mm
	SOIC (8) <sup>(3)</sup>	4.90 mm x 3.90 mm
OPA4397 <sup>(2)</sup>	TSSOP (14) <sup>(3)</sup>	5.00 mm x 4.40 mm
	QFN (16) <sup>(3)</sup>	3.00 mm x 3.00 mm

- (1) For all available packages, see the package option addendum at the end of the data sheet.
- (2) Device is preview.
- (3) Package is preview.



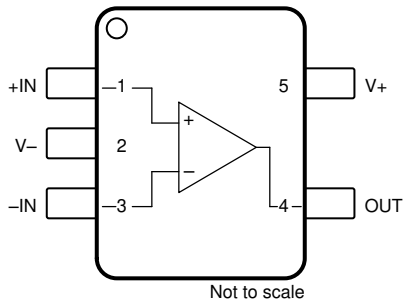
## Table of Contents

<b>1 Features</b> .....	<b>1</b>	<b>8 Application and Implementation</b> .....	<b>17</b>
<b>2 Applications</b> .....	<b>1</b>	8.1 Application Information.....	17
<b>3 Description</b> .....	<b>1</b>	8.2 Typical Application.....	17
<b>4 Revision History</b> .....	<b>2</b>	<b>9 Power Supply Recommendations</b> .....	<b>20</b>
<b>5 Pin Configuration and Functions</b> .....	<b>3</b>	<b>10 Layout</b> .....	<b>20</b>
<b>6 Specifications</b> .....	<b>6</b>	10.1 Layout Guidelines.....	20
6.1 Absolute Maximum Ratings .....	6	10.2 Layout Example.....	20
6.2 ESD Ratings .....	6	<b>11 Device and Documentation Support</b> .....	<b>21</b>
6.3 Recommended Operating Conditions .....	6	11.1 Device Support.....	21
6.4 Thermal Information .....	6	11.2 Documentation Support.....	21
6.5 Electrical Characteristics .....	7	11.3 Receiving Notification of Documentation Updates..	21
6.6 Typical Characteristics.....	9	11.4 Support Resources.....	21
<b>7 Detailed Description</b> .....	<b>15</b>	11.5 Trademarks.....	21
7.1 Overview.....	15	11.6 Electrostatic Discharge Caution.....	21
7.2 Functional Block Diagram.....	15	11.7 Glossary.....	21
7.3 Feature Description.....	16	<b>12 Mechanical, Packaging, and Orderable</b>	
7.4 Device Functional Modes.....	16	<b>Information</b> .....	<b>22</b>

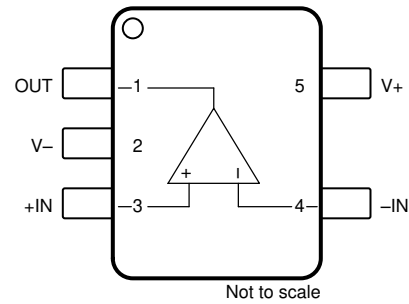
## 4 Revision History

DATE	REVISION	NOTES
August 2021	*	Initial Release

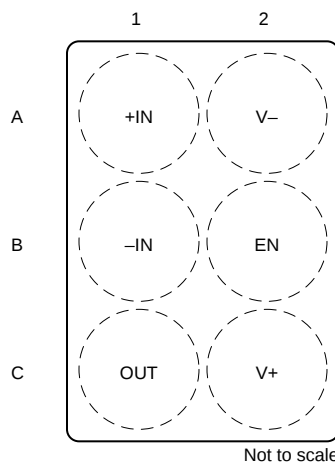
## 5 Pin Configuration and Functions



**Figure 5-1. OPA397 DCK Package (5-Pin SOT, Preview), Top View**



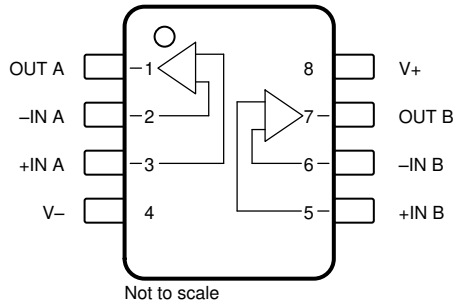
**Figure 5-2. OPA397 DBV Package (5-Pin SOT-23), Top View**



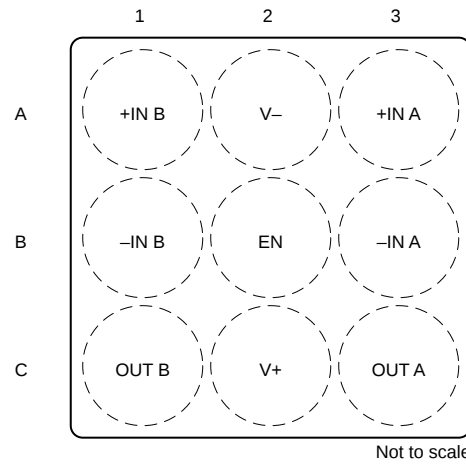
**Figure 5-3. OPA397 YCJ Package (6-Pin DSBGA, Preview), Top View**

**Table 5-1. Pin Functions: OPA397**

NAME	PIN			I/O	DESCRIPTION
	NO.				
	DBV (SOT-23)	DCK (SC-70)	YCJ (DSBGA)		
-IN	4	3	B1	I	Inverting input
+IN	3	1	A1	I	Noninverting input
EN	—	—	B2	I	Enable pin. High = amplifier enabled.
OUT	1	4	C1	O	Output
V-	2	2	A2	—	Negative (lowest) power supply
V+	5	5	C2	—	Positive (highest) power supply



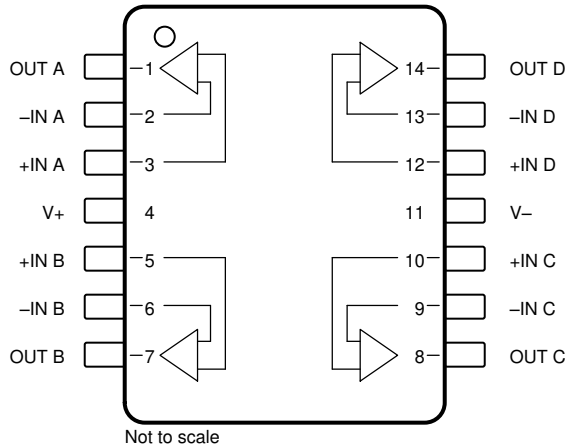
**Figure 5-4. OPA2397 D (8-Pin SOIC, Preview) and DGK (8-Pin MSOP, Preview) Packages, Top View**



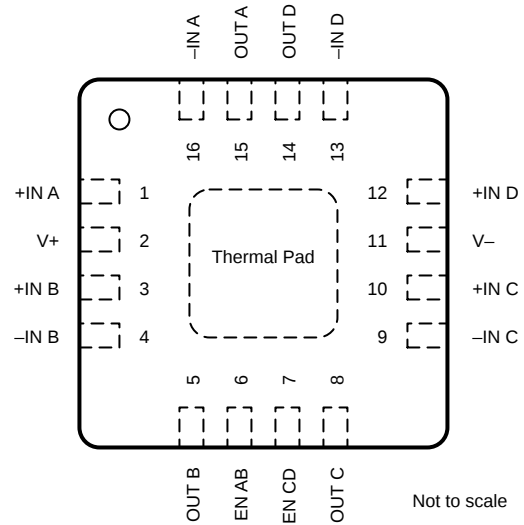
**Figure 5-5. OPA2397 YBJ (9-Pin DSBGA, Preview) Package, Top View**

**Table 5-2. Pin Functions: OPA2397**

NAME	PIN		I/O	DESCRIPTION
	NO.			
	D (SOIC), DGK (VSSOP)	YBJ (DSBGA)		
-IN A	2	B3	I	Inverting input, channel A
-IN B	6	B1	I	Inverting input, channel B
+IN A	3	A3	I	Noninverting input, channel A
+IN B	5	A1	I	Noninverting input, channel B
EN	—	B2	I	Enable pin. High = both amplifiers enabled.
OUT A	1	C3	O	Output, channel A
OUT B	7	C1	O	Output, channel B
V-	4	A2	—	Negative (lowest) power supply
V+	8	C2	—	Positive (highest) power supply



**Figure 5-6. OPA4397 PW (14-Pin TSSOP, Preview)  
Package, Top View**



**Figure 5-7. OPA4397 RTE (16-Pin QFN, Preview)  
Package, Top View**

**Table 5-3. Pin Functions: OPA4397**

NAME	PIN		I/O	DESCRIPTION
	NO.			
	PW (TSSOP)	RTE (QFN)		
-IN A	2	16	I	Inverting input, channel A
-IN B	6	4	I	Inverting input, channel B
-IN C	9	9	I	Inverting input, channel C
-IN D	13	13	I	Inverting input, channel D
+IN A	3	1	I	Noninverting input, channel A
+IN B	5	3	I	Noninverting input, channel B
+IN C	10	10	I	Noninverting input, channel C
+IN D	12	12	I	Noninverting input, channel D
EN AB	—	6	I	Enable pin for A and B amplifiers. High = amplifiers A and B are enabled.
EN CD	—	7	I	Enable pin for C and D amplifiers. High = amplifiers C and D are enabled.
OUT A	1	15	O	Output, channel A
OUT B	7	5	O	Output, channel B
OUT C	8	8	O	Output, channel C
OUT D	14	14	O	Output, channel D
Thermal Pad	—	Thermal Pad	—	Connect thermal pad to V-
V-	11	11	—	Negative (lowest) power supply
V+	4	2	—	Positive (highest) power supply

## 6 Specifications

### 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

			MIN	MAX	UNIT
V <sub>S</sub>	Supply voltage, V <sub>S</sub> = (V+) – (V–)	Single-supply		6	V
		Dual-supply		±3	
	Input voltage, all pins	Common-mode	(V–) – 0.5	(V+) + 0.5	V
		Differential		(V+) – (V–) + 0.2	
	Input current, all pins			±10	mA
	Output short circuit <sup>(2)</sup>		Continuous	Continuous	
T <sub>A</sub>	Operating temperature		–55	150	°C
T <sub>J</sub>	Junction temperature		–55	150	°C
T <sub>stg</sub>	Storage temperature		–65	150	°C

- (1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.
- (2) Short-circuit to ground, one amplifier per package.

### 6.2 ESD Ratings

			VALUE	UNIT
V <sub>(ESD)</sub>	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	2000	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	500	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

			MIN	NOM	MAX	UNIT
V <sub>S</sub>	Supply voltage	Single-supply	1.7		5.5	V
		Dual-supply	±0.85		±2.75	
T <sub>A</sub>	Specified temperature	Specified temperature	–40		+125	°C

### 6.4 Thermal Information

THERMAL METRIC <sup>(1)</sup>		OPA397	UNIT
		DBV (SOT-23)	
		5 PINS	
R <sub>θJA</sub>	Junction-to-ambient thermal resistance	187.1	°C/W
R <sub>θJC(top)</sub>	Junction-to-case (top) thermal resistance	107.4	°C/W
R <sub>θJB</sub>	Junction-to-board thermal resistance	57.5	°C/W
Ψ <sub>JT</sub>	Junction-to-top characterization parameter	33.5	°C/W
Ψ <sub>JB</sub>	Junction-to-board characterization parameter	57.1	°C/W
R <sub>θJC(bot)</sub>	Junction-to-case (bottom) thermal resistance	N/A	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

## 6.5 Electrical Characteristics

at  $T_A = 25^\circ\text{C}$ ,  $V_S = 1.7\text{ V to }5.5\text{ V}$  (single-supply) or  $V_S = \pm 0.85\text{ V to } \pm 2.75\text{ V}$  (dual-supply),  $R_L = 10\text{ k}\Omega$  connected to  $V_S / 2$ ,  $V_{CM} = V_S / 2$ , and  $V_{OUT} = V_S / 2$  (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
<b>OFFSET VOLTAGE</b>							
$V_{OS}$	Input offset voltage	$V_S = 5.0\text{ V}$	$V_{CM} = (V+) - 200\text{ mV}$		$\pm 10$	$\pm 60$	$\mu\text{V}$
			$T_A = -40^\circ\text{C to } +125^\circ\text{C}$		$\pm 20$	$\pm 100$	
			$V_{CM} = (V-), T_A = -40^\circ\text{C to } 125^\circ\text{C}$			$\pm 200$	
						$\pm 125$	
$dV_{OS}/dT$	Input offset voltage drift	$V_S = 5.0\text{ V}$	$T_A = 0^\circ\text{C to } 85^\circ\text{C}$		$\pm 0.16$		$\mu\text{V}/^\circ\text{C}$
			$T_A = -40^\circ\text{C to } +125^\circ\text{C}$			$\pm 1$	
			$V_{CM} = 5.0\text{ V}, T_A = -40^\circ\text{C to } +125^\circ\text{C}$		$\pm 0.18$	$\pm 1.5$	
PSRR	Power supply rejection ratio	$V_{CM} = (V-)$				$\pm 30$	$\mu\text{V}/\text{V}$
			$T_A = -40^\circ\text{C to } +125^\circ\text{C}$				
<b>INPUT BIAS CURRENT</b>							
$I_B$	Input bias current				$\pm 0.01$	$\pm 1$	$\text{pA}$
		$T_A = -40^\circ\text{C to } +85^\circ\text{C}$				$\pm 10$	
		$T_A = -40^\circ\text{C to } +125^\circ\text{C}$					
$I_{OS}$	Input offset current				$\pm 0.01$	$\pm 0.8$	$\text{pA}$
		$T_A = -40^\circ\text{C to } +85^\circ\text{C}$				$\pm 5$	
		$T_A = -40^\circ\text{C to } +125^\circ\text{C}$					
<b>NOISE</b>							
	Input voltage noise	$f = 0.1\text{ Hz to } 10\text{ Hz}$			2.0		$\mu\text{V}_{PP}$
			$V_{CM} = (V+) - 0.3$			3.2	
$e_N$	Input voltage noise density	$f = 10\text{ Hz}$			42		$\text{nV}/\sqrt{\text{Hz}}$
			$V_{CM} = (V+) - 0.3$			80	
		$f = 1\text{ kHz}$			6.5		
			$V_{CM} = (V+) - 0.3$			10.4	
		$f = 10\text{ kHz}$			4.4		
			$V_{CM} = (V+) - 0.3$			5.8	
$i_N$	Input current noise	$f = 1\text{ kHz}$			70		$\text{fA}/\sqrt{\text{Hz}}$
<b>INPUT VOLTAGE</b>							
$V_{CM}$	Common-mode voltage range			(V-)		(V+)	V
CMRR	Common-mode rejection ratio	$(V-) < V_{CM} < (V+) - 1.5\text{ V}$		75	120		dB
			$T_A = -40^\circ\text{C to } +125^\circ\text{C}$		113		
		$(V-) < V_{CM} < (V+), T_A = -40^\circ\text{C to } +125^\circ\text{C}$		66	97		
			$V_S = 5.5\text{ V}$	88	111		
<b>INPUT CAPACITANCE</b>							
$Z_{ID}$	Differential				$10^{13} \parallel 2.8$		$\Omega \parallel \text{pF}$
$Z_{ICM}$	Common-mode				$10^{13} \parallel 3.5$		$\Omega \parallel \text{pF}$

## 6.5 Electrical Characteristics (continued)

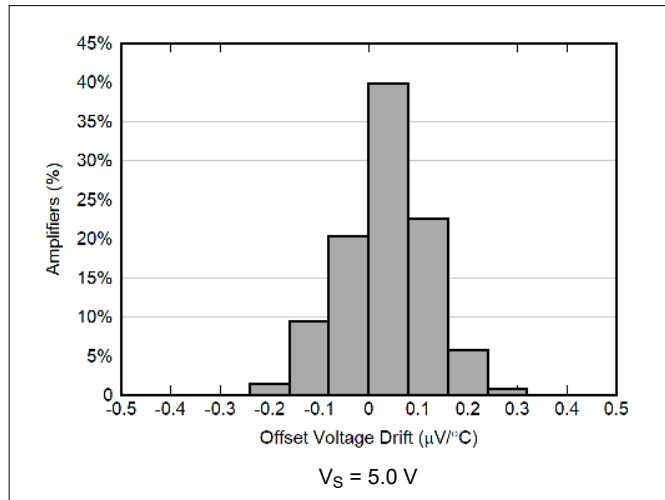
at  $T_A = 25^\circ\text{C}$ ,  $V_S = 1.7\text{ V}$  to  $5.5\text{ V}$  (single-supply) or  $V_S = \pm 0.85\text{ V}$  to  $\pm 2.75\text{ V}$  (dual-supply),  $R_L = 10\text{ k}\Omega$  connected to  $V_S / 2$ ,  $V_{CM} = V_S / 2$ , and  $V_{OUT} = V_S / 2$  (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
<b>OPEN-LOOP GAIN</b>							
$A_{OL}$	Open-loop voltage gain	$V_S = 5.5$	$(V^-) + 50\text{ mV} < V_{OUT} < (V^+) - 50\text{ mV}$ , $R_L = 10\text{ k}\Omega$	115	132		dB
			$(V^-) + 100\text{ mV} < V_{OUT} < (V^+) - 100\text{ mV}$ , $R_L = 2\text{ k}\Omega$	110	128		
			$(V^-) + 100\text{ mV} < V_{OUT} < (V^+) - 100\text{ mV}$ , $R_L = 2\text{ k}\Omega$ , $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$	100			
		$V_S = 1.7$	$(V^-) + 50\text{ mV} < V_{OUT} < (V^+) - 50\text{ mV}$ , $R_L = 10\text{ k}\Omega$ , $V_{CM} = (V^+) - 1.15\text{ V}$	106	124		
			$(V^-) + 100\text{ mV} < V_{OUT} < (V^+) - 100\text{ mV}$ , $R_L = 2\text{ k}\Omega$ , $V_{CM} = (V^+) - 1.15\text{ V}$	106	124		
			$(V^-) + 100\text{ mV} < V_{OUT} < (V^+) - 100\text{ mV}$ , $R_L = 2\text{ k}\Omega$ , $V_{CM} = (V^+) - 1.15\text{ V}$ , $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$	100			
<b>FREQUENCY RESPONSE</b>							
GBW	Gain-bandwidth product	$A_V = 1000\text{ V/V}$			13		MHz
SR	Slew rate	4-V step, gain = +1	falling		4.5		V/ $\mu\text{s}$
			rising		3.5		V/ $\mu\text{s}$
	Phase margin	$C_L = 100\text{ pF}$			45		$^\circ$
$t_S$	Settling time	To 0.1%, 2-V step, gain = +1			0.75		$\mu\text{s}$
		To 0.01%, 2-V step, gain = +1			1		
	Overload recovery time	$V_{IN} \times \text{gain} > V_S$			0.45		$\mu\text{s}$
THD+N	Total harmonic distortion + noise	$V_{OUT} = 1\text{ V}_{RMS}$ , gain = +1, $f = 1\text{ kHz}$ , $R_L = 10\text{ k}\Omega$ , $V_{CM} = (V^-) + 1.5\text{ V}$			-112		dB
					0.00025		%
<b>OUTPUT</b>							
	Voltage output swing from both rails	$V_S = 1.7\text{ V}$	$R_L = 10\text{ k}\Omega$			20	mV
			$R_L = 2\text{ k}\Omega$			30	
		$V_S = 5.5\text{ V}$	$R_L = 10\text{ k}\Omega$			20	
			$R_L = 2\text{ k}\Omega$			35	
$I_{SC}$	Short-circuit current	Sinking, $V_S = 5.5\text{ V}$			-55		mA
		Sourcing, $V_S = 5.5\text{ V}$			65		
$R_O$	Open-loop output impedance	$f = 1\text{ MHz}$			120		$\Omega$
<b>POWER SUPPLY</b>							
$I_Q$	Quiescent current per amplifier	$I_O = 0\text{ mA}$			1.22	1.4	mA
		$I_O = 0\text{ mA}$ , $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$				1.5	

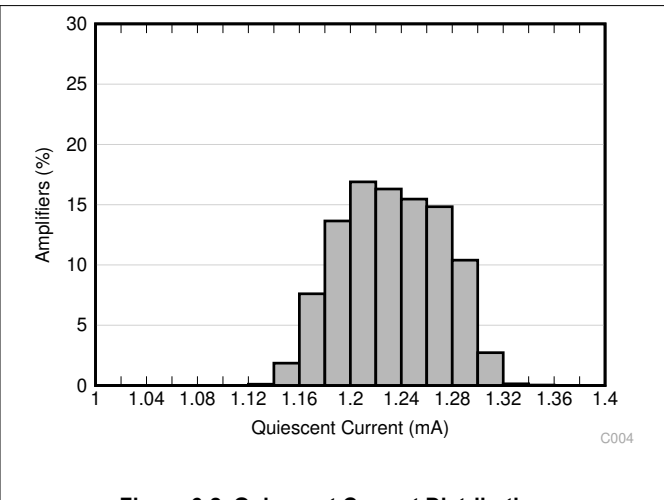


## 6.6 Typical Characteristics

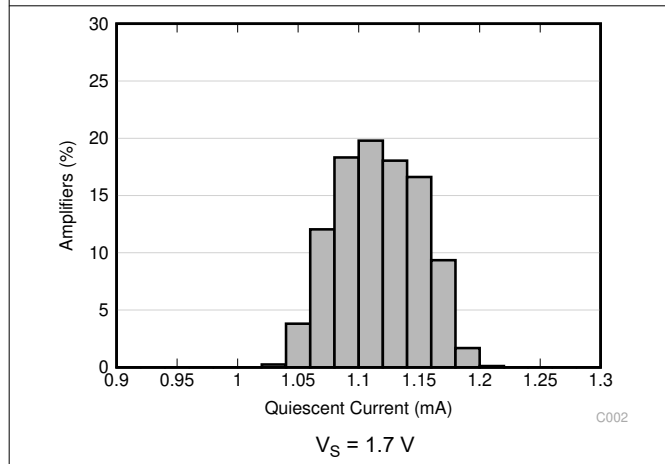
at  $T_A = 25^\circ\text{C}$ ,  $V_S = 5.5\text{ V}$ ,  $V_{CM} = V_S / 2$ ,  $R_{LOAD} = 10\text{ k}\Omega$  connected to  $V_S / 2$ , and  $C_L = 100\text{ pF}$  (unless otherwise noted)



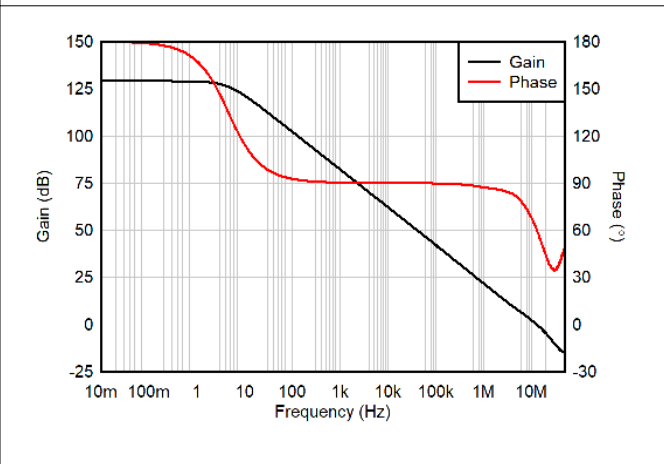
**Figure 6-1. Offset Voltage Distribution**



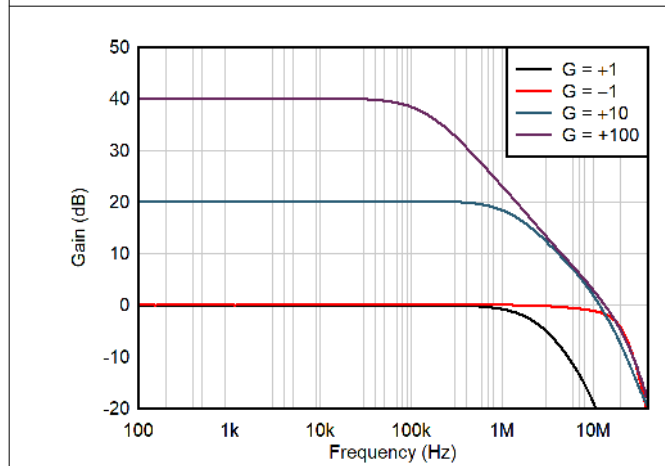
**Figure 6-2. Quiescent Current Distribution**



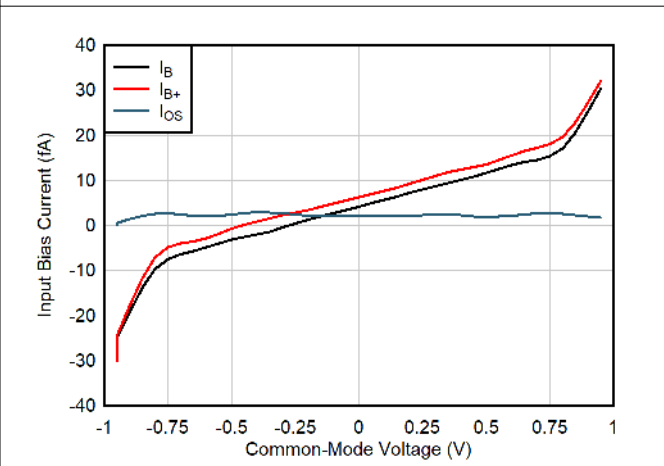
**Figure 6-3. Quiescent Current Distribution**



**Figure 6-4. Open-Loop Gain and Phase vs Frequency**



**Figure 6-5. Closed-Loop Gain and Phase vs Frequency**



**Figure 6-6. Input Bias Current vs Common-Mode Voltage**

### 6.6 Typical Characteristics (continued)

at  $T_A = 25^\circ\text{C}$ ,  $V_S = 5.5\text{ V}$ ,  $V_{CM} = V_S / 2$ ,  $R_{LOAD} = 10\text{ k}\Omega$  connected to  $V_S / 2$ , and  $C_L = 100\text{ pF}$  (unless otherwise noted)

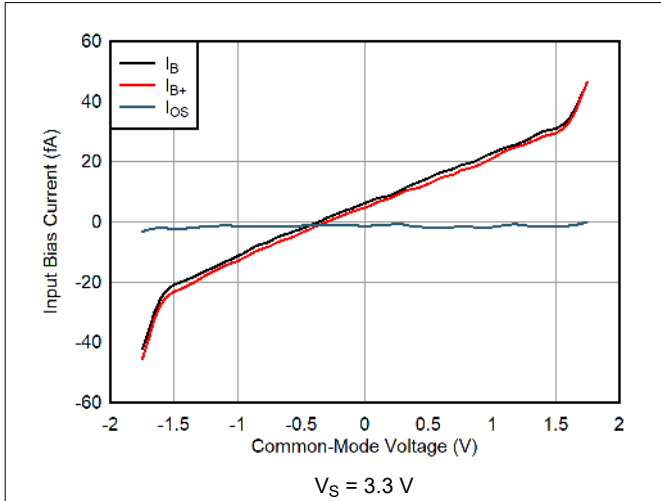


Figure 6-7. Input Bias Current vs Common-Mode Voltage

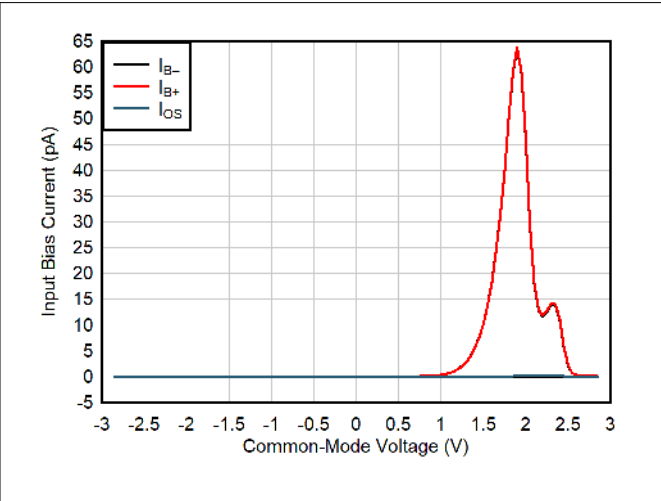


Figure 6-8. Input Bias Current vs Temperature

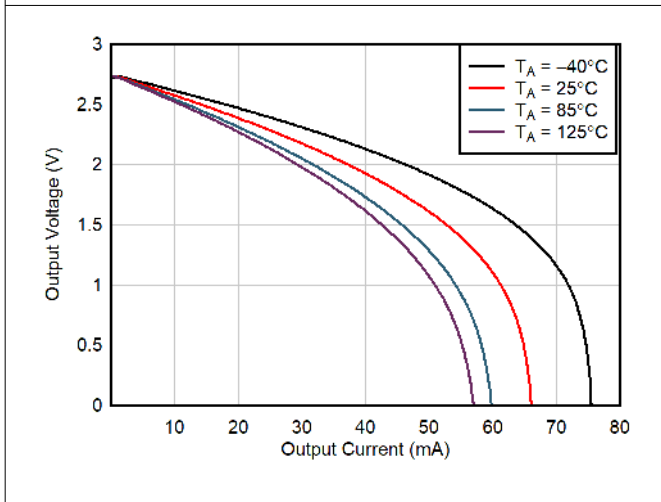


Figure 6-9. Output Voltage Swing vs Output Current (Sourcing)

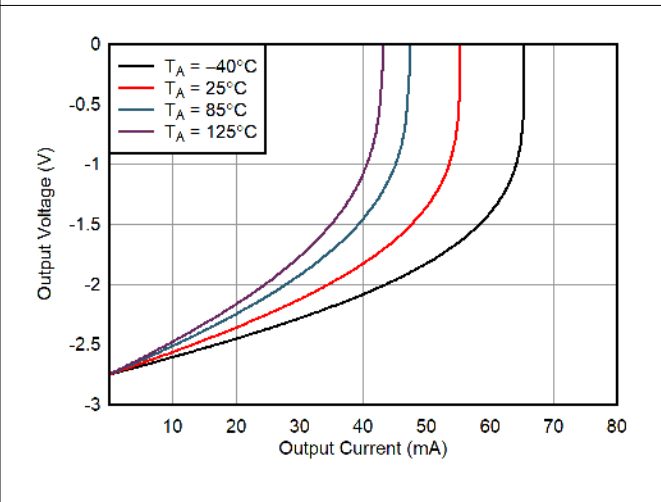


Figure 6-10. Output Voltage Swing vs Output Current (Sinking)

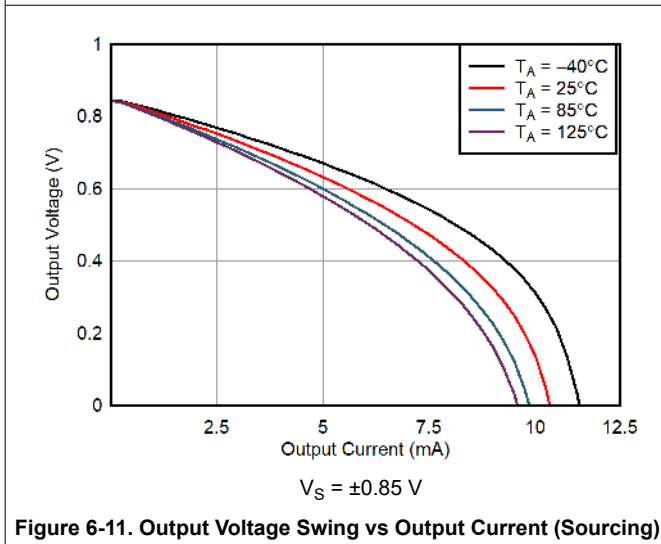


Figure 6-11. Output Voltage Swing vs Output Current (Sourcing)

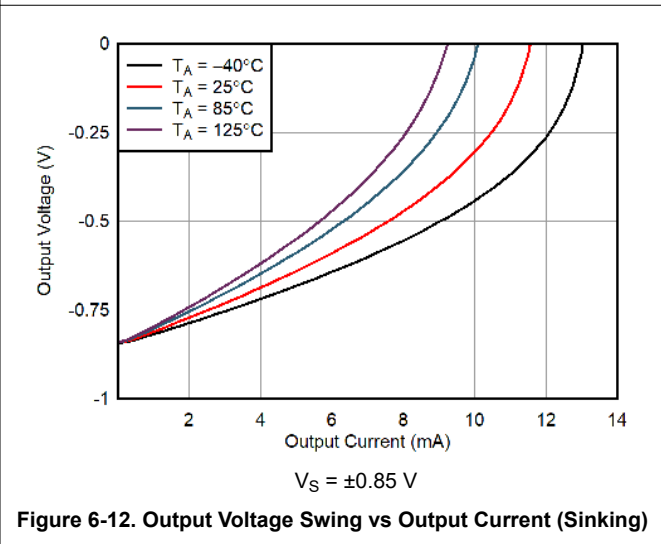
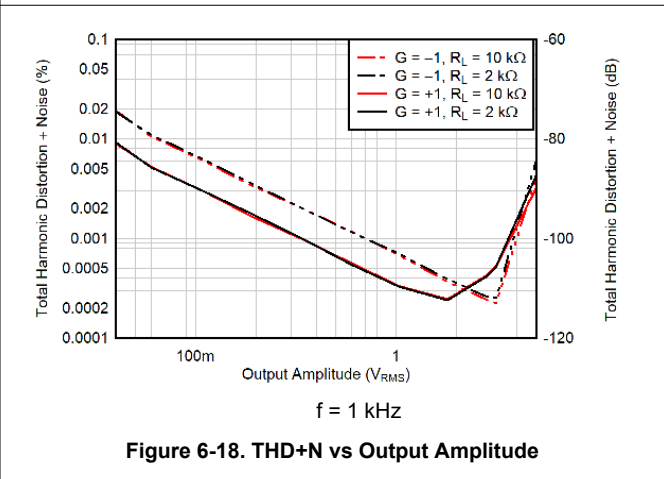
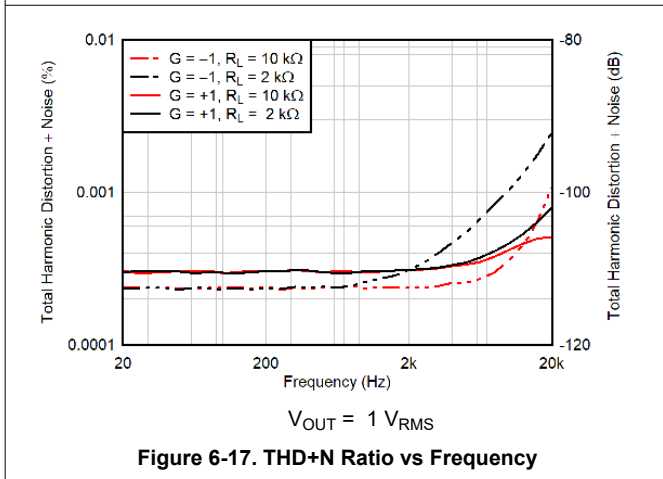
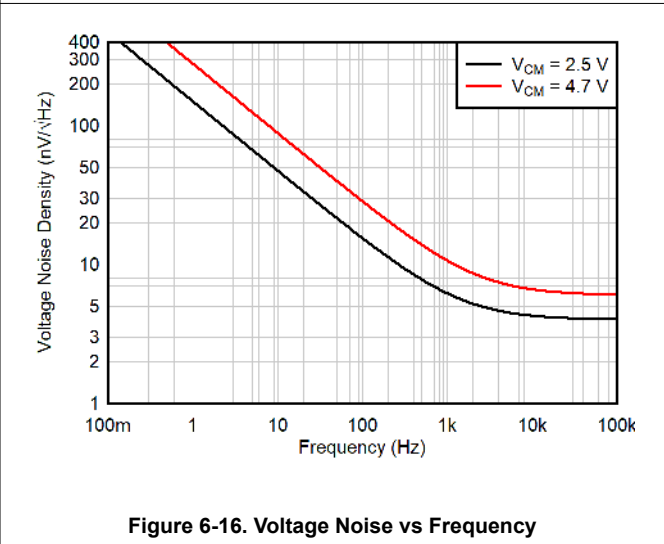
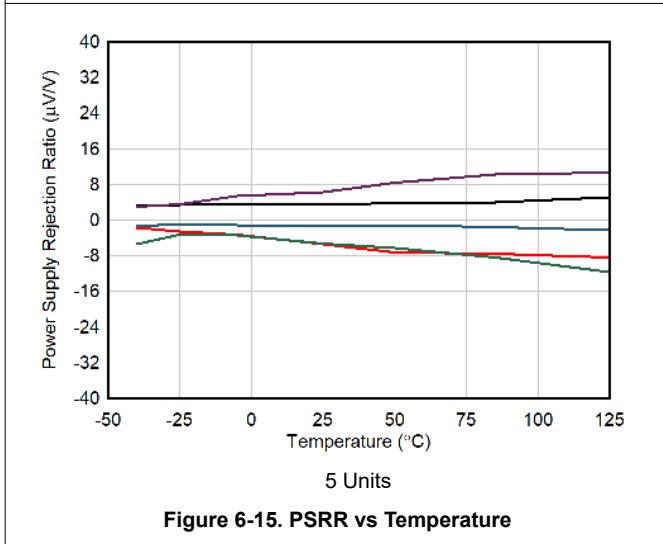
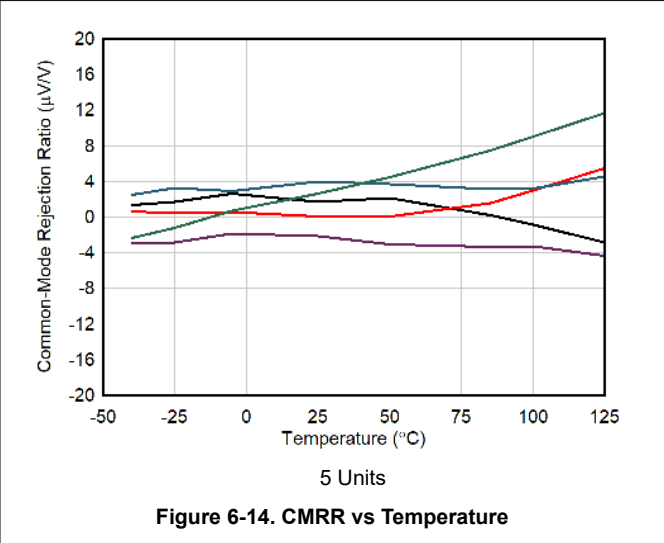
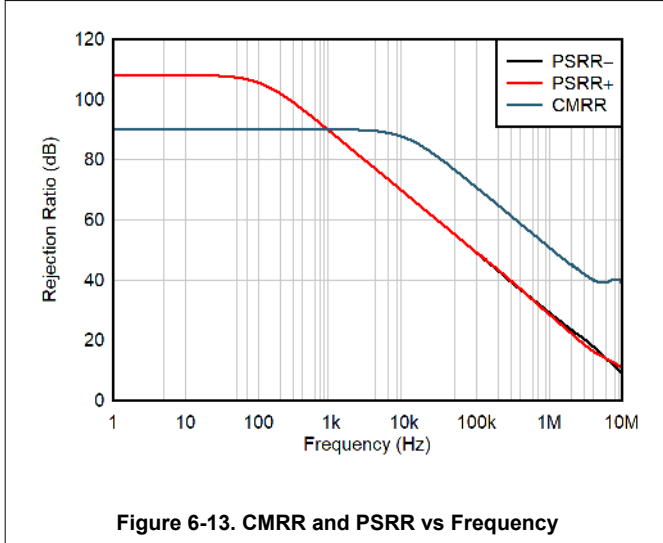


Figure 6-12. Output Voltage Swing vs Output Current (Sinking)

## 6.6 Typical Characteristics (continued)

at  $T_A = 25^\circ\text{C}$ ,  $V_S = 5.5\text{ V}$ ,  $V_{CM} = V_S / 2$ ,  $R_{LOAD} = 10\text{ k}\Omega$  connected to  $V_S / 2$ , and  $C_L = 100\text{ pF}$  (unless otherwise noted)



## 6.6 Typical Characteristics (continued)

at  $T_A = 25^\circ\text{C}$ ,  $V_S = 5.5\text{ V}$ ,  $V_{CM} = V_S / 2$ ,  $R_{LOAD} = 10\text{ k}\Omega$  connected to  $V_S / 2$ , and  $C_L = 100\text{ pF}$  (unless otherwise noted)

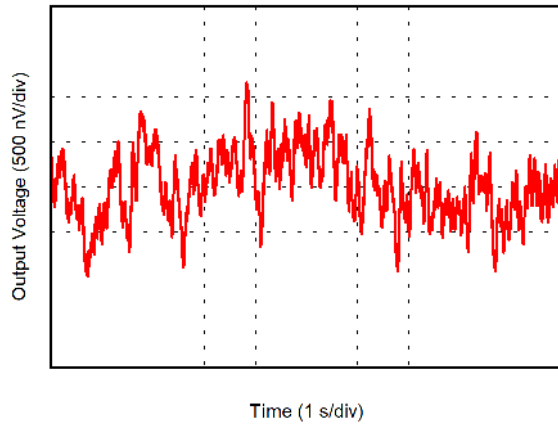


Figure 6-19. 0.1-Hz to 10-Hz Noise

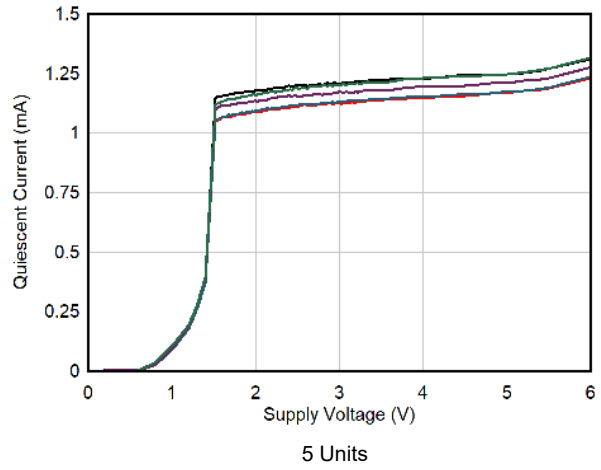


Figure 6-20. Quiescent Current vs Supply Voltage

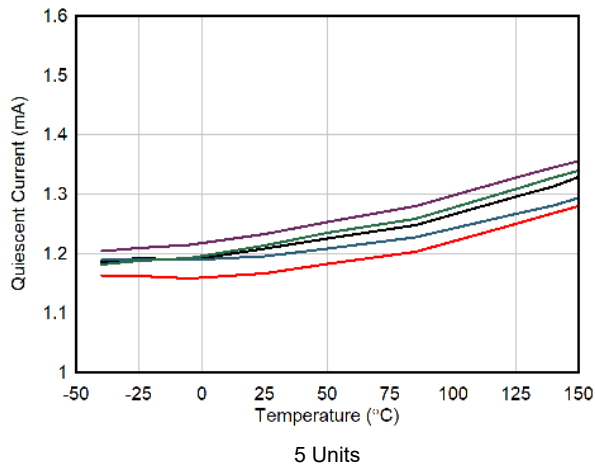


Figure 6-21. Quiescent Current vs Temperature

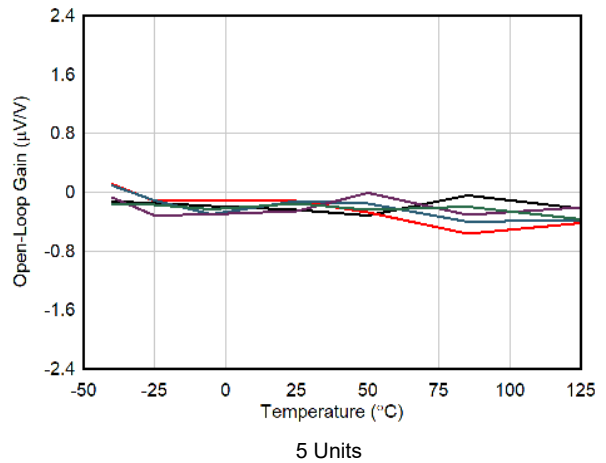


Figure 6-22. Open-Loop Gain vs Temperature

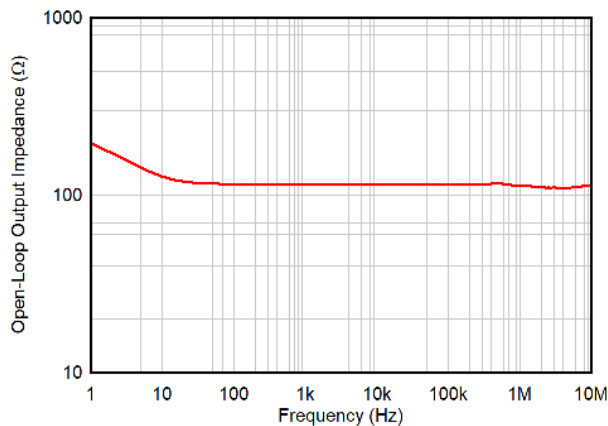


Figure 6-23. Open-Loop Output Impedance vs Frequency

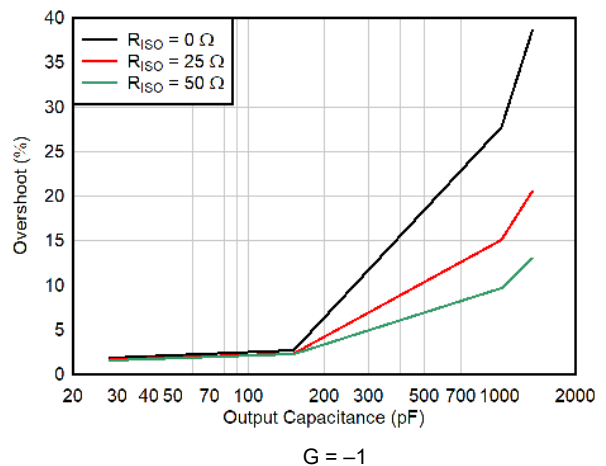
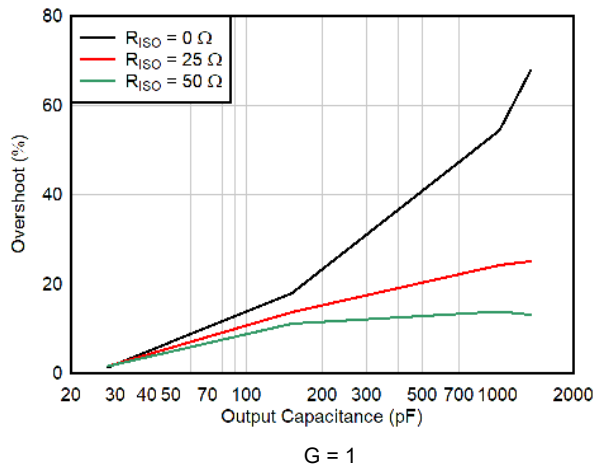


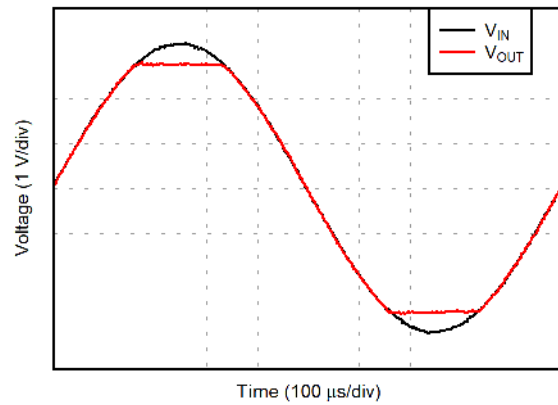
Figure 6-24. Small-Signal Overshoot vs Capacitive Load (10-mV Step)

## 6.6 Typical Characteristics (continued)

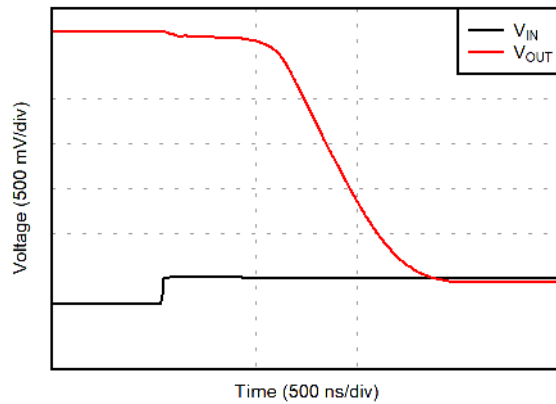
at  $T_A = 25^\circ\text{C}$ ,  $V_S = 5.5\text{ V}$ ,  $V_{CM} = V_S / 2$ ,  $R_{LOAD} = 10\text{ k}\Omega$  connected to  $V_S / 2$ , and  $C_L = 100\text{ pF}$  (unless otherwise noted)



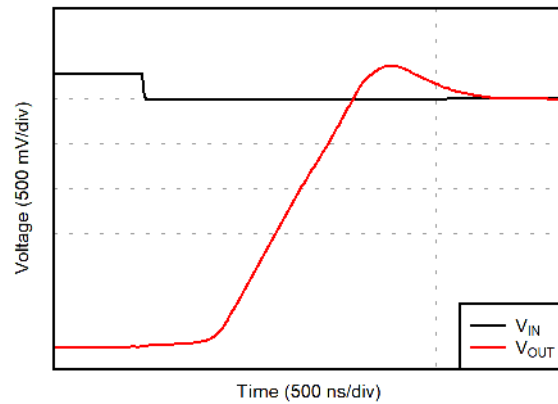
**Figure 6-25. Small-Signal Overshoot vs Capacitive Load (10-mV Step)**  
 $G = 1$



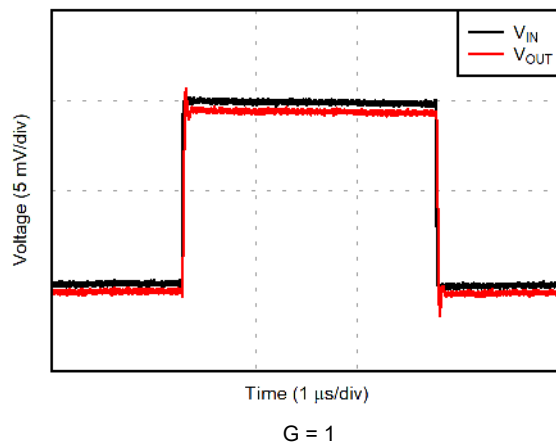
**Figure 6-26. No Phase Reversal**



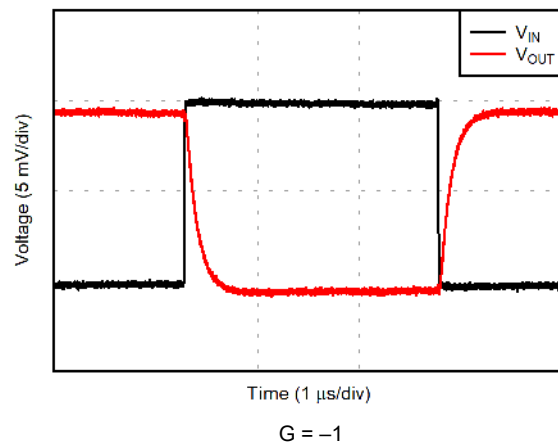
**Figure 6-27. Positive Overload Recovery**



**Figure 6-28. Negative Overload Recovery**



**Figure 6-29. Small-Signal Step Response (10-mV Step)**  
 $G = 1$



**Figure 6-30. Small-Signal Step Response (10-mV Step)**  
 $G = -1$

## 6.6 Typical Characteristics (continued)

at  $T_A = 25^\circ\text{C}$ ,  $V_S = 5.5\text{ V}$ ,  $V_{CM} = V_S / 2$ ,  $R_{LOAD} = 10\text{ k}\Omega$  connected to  $V_S / 2$ , and  $C_L = 100\text{ pF}$  (unless otherwise noted)

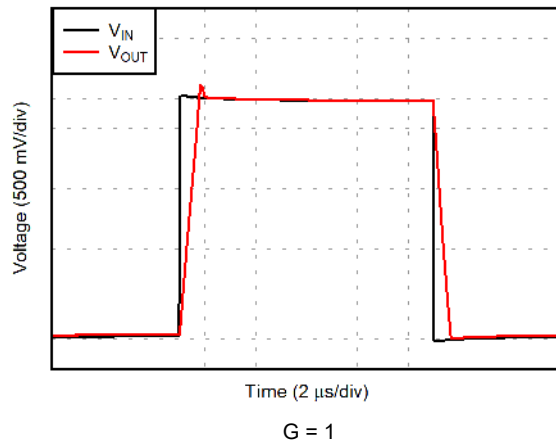


Figure 6-31. Large-Signal Step Response (4-V Step)

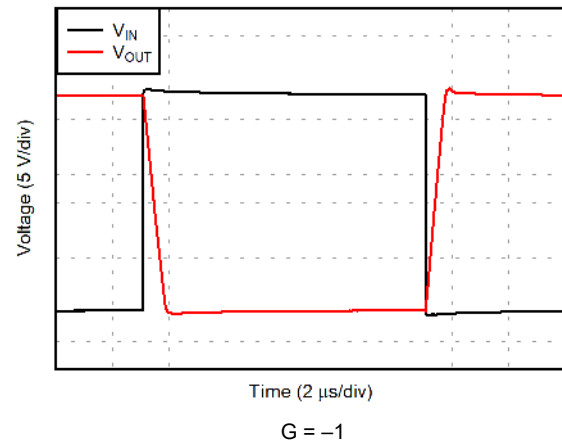


Figure 6-32. Large-Signal Step Response (4-V Step)

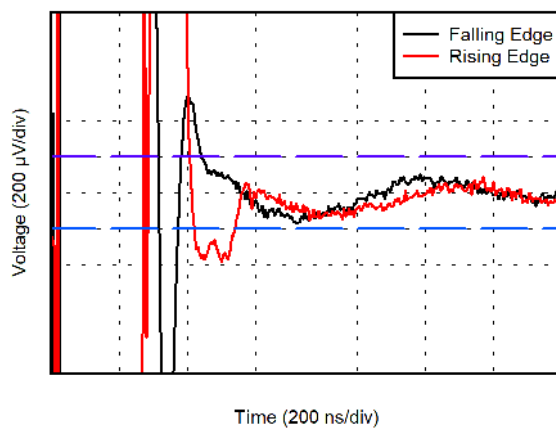


Figure 6-33. Settling Time

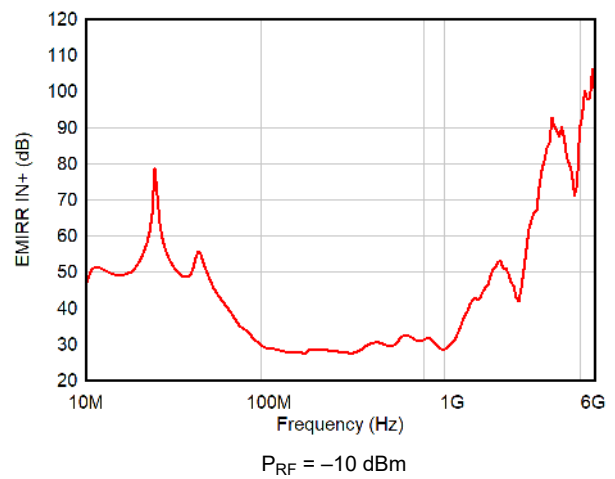


Figure 6-34. EMIRR vs Frequency

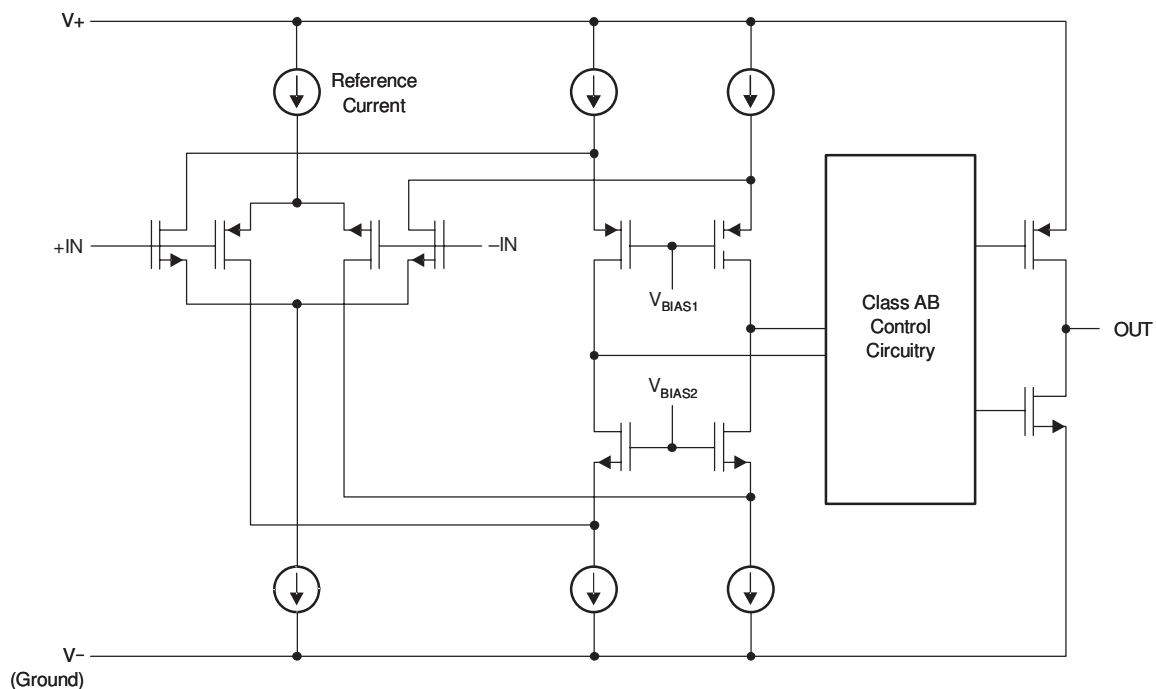
## 7 Detailed Description

### 7.1 Overview

The OPAx397 is a family of low offset, low-noise e-trim operational amplifiers (op amps) that uses a proprietary offset trim technique. These op amps offer ultra-low input offset voltage and drift and achieve excellent input and output dynamic linearity. The OPAx397 operate from 1.7 V to 5.5 V, are unity-gain stable, and are designed for a wide range of general-purpose and precision applications.

The amplifiers feature state-of-the-art CMOS technology and advanced design features that help achieve extremely low input bias current, wide input and output voltage ranges, high loop gain, and low, flat output impedance in small package options. The OPAx397 strengths also include 13-MHz bandwidth, 4.4-nV/ $\sqrt{\text{Hz}}$  noise spectral density, and low  $1/f$  noise. These features make the OPAx397 an exceptional choice for interfacing with sensors, photodiodes, and high-performance analog-to-digital converters (ADCs).

### 7.2 Functional Block Diagram



## 7.3 Feature Description

### 7.3.1 Low Operating Voltage

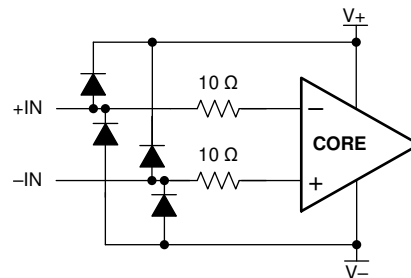
The OPAx397 family can be used with single or dual supplies from an operating range of  $V_S = 1.7\text{ V}$  ( $\pm 0.85\text{ V}$ ) up to  $5.5\text{ V}$  ( $\pm 2.75\text{ V}$ ). The offset voltage is trimmed at  $5.0\text{ V}$ , however, the device maintains ultra-low offset voltages down to  $V_S = 1.7\text{ V}$ .

Key parameters that vary over the supply voltage or temperature range are shown in the *Typical Characteristics*.

### 7.3.2 Low Input Bias Current

The typical input bias current of the OPAx397 is extremely low (typically  $10\text{ fA}$ ). Input bias current is dominated by leakage current from the ESD protection diodes, which is proportional to the area of the diode. The OPAx397 is able to achieve ultra-low input bias current as a result of modern process technology and advanced ESD protection design that minimizes the area of the diode.

In overdriven conditions, the bias current can increase significantly. The most common cause of an overdriven condition occurs when the operational amplifier is outside of the linear range of operation. When the output of the operational amplifier is driven to one of the supply rails, the feedback loop requirements cannot be satisfied and a differential input voltage develops across the input pins. This differential input voltage results in the forward-biasing of the ESD cells. The equivalent circuit is shown in [Figure 7-1](#).



**Figure 7-1. Equivalent Input Circuit**

## 7.4 Device Functional Modes

The OPAx397 family is operational when the power-supply voltage is greater than  $1.7\text{ V}$  ( $\pm 0.85\text{ V}$ ). For devices that use the EN function (see [Section 5](#)), the devices are disabled when the EN pin is low. In this state, quiescent current is significantly reduced, and the output is high impedance. The maximum specified power-supply voltage for the OPAx397 is  $5.5\text{ V}$  ( $\pm 2.75\text{ V}$ ).



## 8 Application and Implementation

### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

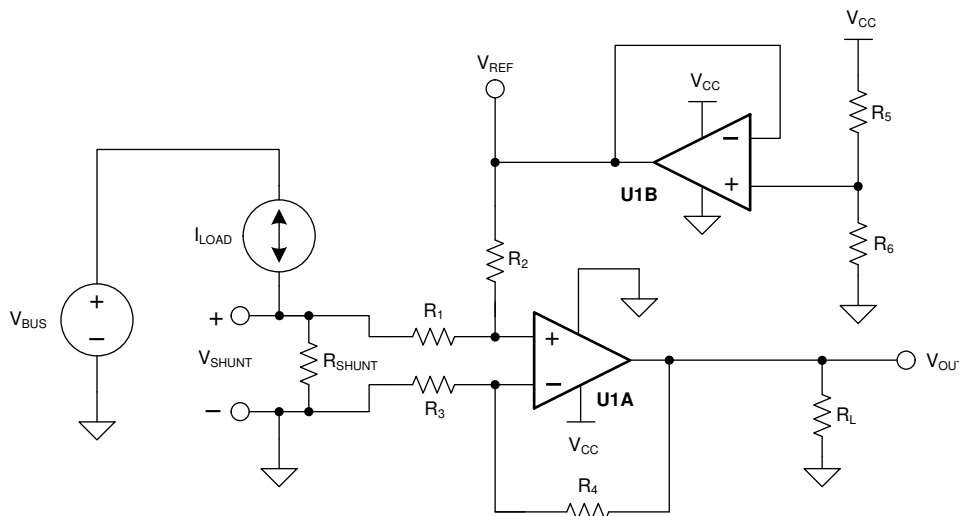
### 8.1 Application Information

The OPAx397 is a unity-gain stable, precision operational amplifier family free from unexpected output and phase reversal. The use of proprietary e-trim operational amplifier technology gives the benefit of low input offset voltage over time and temperature, along with ultra-low input bias current. The OPAx397 are optimized for full rail-to-rail input, allowing for low-voltage, single-supply operation or split-supply use. These miniature, high-precision, low-noise amplifiers offer high-impedance inputs that have a common-mode range to the supply rail, with low offset across the supply range, and a rail-to-rail output that swings within 5 mV of the supplies under normal test conditions. The OPAx397 precision amplifiers are designed for upstream analog signal chain applications in low or high gains, as well as downstream signal chain functions such as DAC buffering.

### 8.2 Typical Application

This single-supply, low-side, bidirectional current-sensing design example detects load currents from  $-1$  A to  $+1$  A. The single-ended output spans from 110 mV to 3.19 V. This design uses the OPA397 because of the low offset voltage and rail-to-rail input and output. One of the amplifiers is configured as a difference amplifier and the other amplifier provides the reference voltage.

Figure 8-1 shows the schematic.



**Figure 8-1. Bidirectional Current-Sensing Schematic**

### 8.2.1 Design Requirements

This solution has the following requirements:

- Supply voltage: 3.3 V
- Input: –1 A to +1 A
- Output: 1.65 V ±1.54 V (110 mV to 3.19 V)

### 8.2.2 Detailed Design Procedure

The load current,  $I_{LOAD}$ , flows through the shunt resistor,  $R_{SHUNT}$ , to develop the shunt voltage,  $V_{SHUNT}$ . The shunt voltage is then amplified by the difference amplifier consisting of U1A and  $R_1$  through  $R_4$ . The gain of the difference amplifier is set by the ratio of  $R_4$  to  $R_3$ . To minimize errors, set  $R_2 = R_4$  and  $R_1 = R_3$ . The reference voltage,  $V_{REF}$ , is supplied by buffering a resistor divider using U1B. The transfer function is given by [Equation 1](#).

$$V_{OUT} = V_{SHUNT} \times \text{Gain}_{\text{Diff\_Amp}} + V_{REF} \quad (1)$$

where

- $V_{SHUNT} = I_{LOAD} \times R_{SHUNT}$
- $\text{Gain}_{\text{Diff\_Amp}} = \frac{R_4}{R_3}$
- $V_{REF} = V_{CC} \times \left[ \frac{R_6}{R_5 + R_6} \right]$

There are two types of errors in this design: offset and gain. Gain errors are introduced by the tolerance of the shunt resistor and the ratios of  $R_4$  to  $R_3$  and, similarly,  $R_2$  to  $R_1$ . Offset errors are introduced by the voltage divider ( $R_5$  and  $R_6$ ) and how closely the ratio of  $R_4 / R_3$  matches  $R_2 / R_1$ . The latter value affects the CMRR of the difference amplifier, ultimately translating to an offset error.

The value of  $V_{SHUNT}$  is the ground potential for the system load because  $V_{SHUNT}$  is a low-side measurement. Therefore, a maximum value must be placed on  $V_{SHUNT}$ . In this design, the maximum value for  $V_{SHUNT}$  is set to 100 mV. [Equation 2](#) calculates the maximum value of the shunt resistor given a maximum shunt voltage of 100 mV and maximum load current of 1 A.

$$R_{SHUNT(\text{Max})} = \frac{V_{SHUNT(\text{Max})}}{I_{LOAD(\text{Max})}} = \frac{100 \text{ mV}}{1 \text{ A}} = 100 \text{ m}\Omega \quad (2)$$

The tolerance of  $R_{SHUNT}$  is directly proportional to cost. For this design, a shunt resistor with a tolerance of 0.5% is selected. If greater accuracy is required, select a 0.1% resistor or better.

The load current is bidirectional; therefore, the shunt voltage range is –100 mV to +100 mV. This voltage is divided down by  $R_1$  and  $R_2$  before reaching the operational amplifier, U1A. Make sure that the voltage present at the noninverting node of U1A is within the common-mode range of the device. Therefore, use an operational amplifier, such as the OPA397, that has a common-mode range that extends below the negative supply voltage. Finally, to minimize offset error, the OPA397 has a typical offset voltage of merely  $\pm 0.25 \mu\text{V}$  ( $\pm 5 \mu\text{V}$  maximum).

Given a symmetric load current of –1 A to +1 A, the voltage divider resistors ( $R_5$  and  $R_6$ ) must be equal. To be consistent with the shunt resistor, a tolerance of 0.5% is selected. To minimize power consumption, 10-k $\Omega$  resistors are used.

To set the gain of the difference amplifier, the common-mode range and output swing of the OPA397 must be considered. Equation 3 and Equation 4 depict the typical common-mode range and maximum output swing, respectively, of the OPA397 given a 3.3-V supply.

$$-100 \text{ mV} < V_{\text{CM}} < 3.4 \text{ V} \quad (3)$$

$$100 \text{ mV} < V_{\text{OUT}} < 3.2 \text{ V} \quad (4)$$

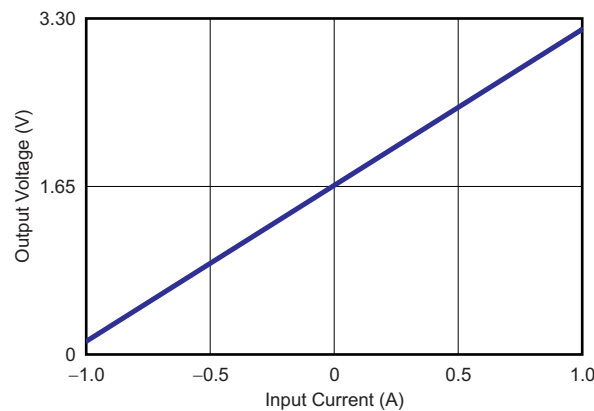
The gain of the difference amplifier can now be calculated as shown in Equation 5:

$$\text{Gain}_{\text{Diff\_Amp}} = \frac{V_{\text{OUT\_Max}} - V_{\text{OUT\_Min}}}{R_{\text{SHUNT}} \times (I_{\text{MAX}} - I_{\text{MIN}})} = \frac{3.2 \text{ V} - 100 \text{ mV}}{100 \text{ m}\Omega \times [1 \text{ A} - (-1 \text{ A})]} = 15.5 \frac{\text{V}}{\text{V}} \quad (5)$$

The resistor value selected for  $R_1$  and  $R_3$  is 1 k $\Omega$ . 15.4 k $\Omega$  is selected for  $R_2$  and  $R_4$  because this number is the nearest standard value. Therefore, the ideal gain of the difference amplifier is 15.4 V/V.

The gain error of the circuit primarily depends on  $R_1$  through  $R_4$ . As a result of this dependence, 0.1% resistors are selected. This configuration reduces the likelihood that the design requires a two-point calibration. A simple one-point calibration, if desired, removes the offset errors introduced by the 0.5% resistors.

### 8.2.3 Application Curve



**Figure 8-2. Bidirectional Current-Sensing Circuit Performance: Output Voltage vs Input Current**

## 9 Power Supply Recommendations

The OPAx397 are specified for operation from 1.7 V to 5.5 V ( $\pm 0.85$  V to  $\pm 2.75$  V).

### CAUTION

Exceeding supply voltages listed in the *Absolute Maximum Ratings* table can permanently damage the device.

## 10 Layout

### 10.1 Layout Guidelines

Pay attention to good layout practice. Keep traces short, and when possible, use a printed-circuit board (PCB) ground plane with surface-mount components placed as close to the device pins as possible. Place a 0.1- $\mu$ F capacitor closely across the supply pins. These guidelines must be applied throughout the analog circuit to improve performance and provide benefits such as reducing the electromagnetic interference (EMI) susceptibility.

For lowest offset voltage and precision performance, circuit layout and mechanical conditions must be optimized. Avoid temperature gradients that create thermoelectric (Seebeck) effects in the thermocouple junctions formed from connecting dissimilar conductors. These thermally-generated potentials can be made to cancel by making sure these potentials are equal on both input terminals. Other layout and design considerations include:

- Use low thermoelectric-coefficient conditions (avoid dissimilar metals).
- Use guard traces to minimize leakage current when ultra-low bias current is required.
- Thermally isolate components from power supplies or other heat sources.
- Shield operational amplifier and input circuitry from air currents, such as cooling fans.

Following these guidelines reduces the likelihood of junctions being at different temperatures, which can cause thermoelectric voltage drift of 0.1  $\mu$ V/ $^{\circ}$ C or higher, depending on materials used.

### 10.2 Layout Example

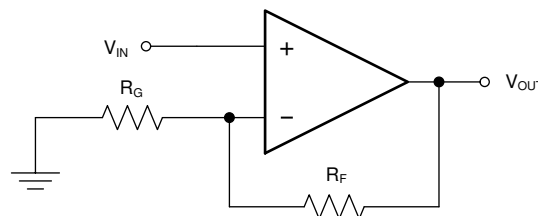


Figure 10-1. OPA397 Layout Schematic

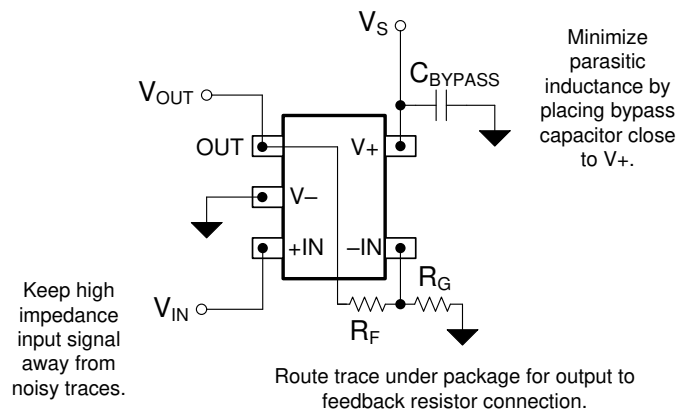


Figure 10-2. OPA397 Layout Example

## 11 Device and Documentation Support

### 11.1 Device Support

#### 11.1.1 Development Support

##### 11.1.1.1 TINA-TI™ Simulation Software (Free Download)

TINA-TI™ simulation software is a simple, powerful, and easy-to-use circuit simulation program based on a SPICE engine. TINA-TI simulation software is a free, fully-functional version of the TINA™ software, preloaded with a library of macromodels, in addition to a range of both passive and active models. TINA-TI simulation software provides all the conventional dc, transient, and frequency domain analysis of SPICE, as well as additional design capabilities.

Available as a [free download](#) from the Analog eLab Design Center, TINA-TI simulation software offers extensive post-processing capability that allows users to format results in a variety of ways. Virtual instruments offer the ability to select input waveforms and probe circuit nodes, voltages, and waveforms, creating a dynamic quick-start tool.

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#### Note

These files require that either the TINA software (from DesignSoft™) or TINA-TI software be installed. Download the free TINA-TI software from the [TINA-TI™ folder](#).

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### 11.2 Documentation Support

#### 11.2.1 Related Documentation

For related documentation see the following:

- [Circuit Board Layout Techniques](#)

### 11.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on [ti.com](#). Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 11.4 Support Resources

[TI E2E™ support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

### 11.5 Trademarks

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TINA™ and DesignSoft™ are trademarks of DesignSoft, Inc.  
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### 11.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### 11.7 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

## 12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
OPA397DBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2JXT	<a href="#">Samples</a>
OPA397DBVT	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2JXT	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

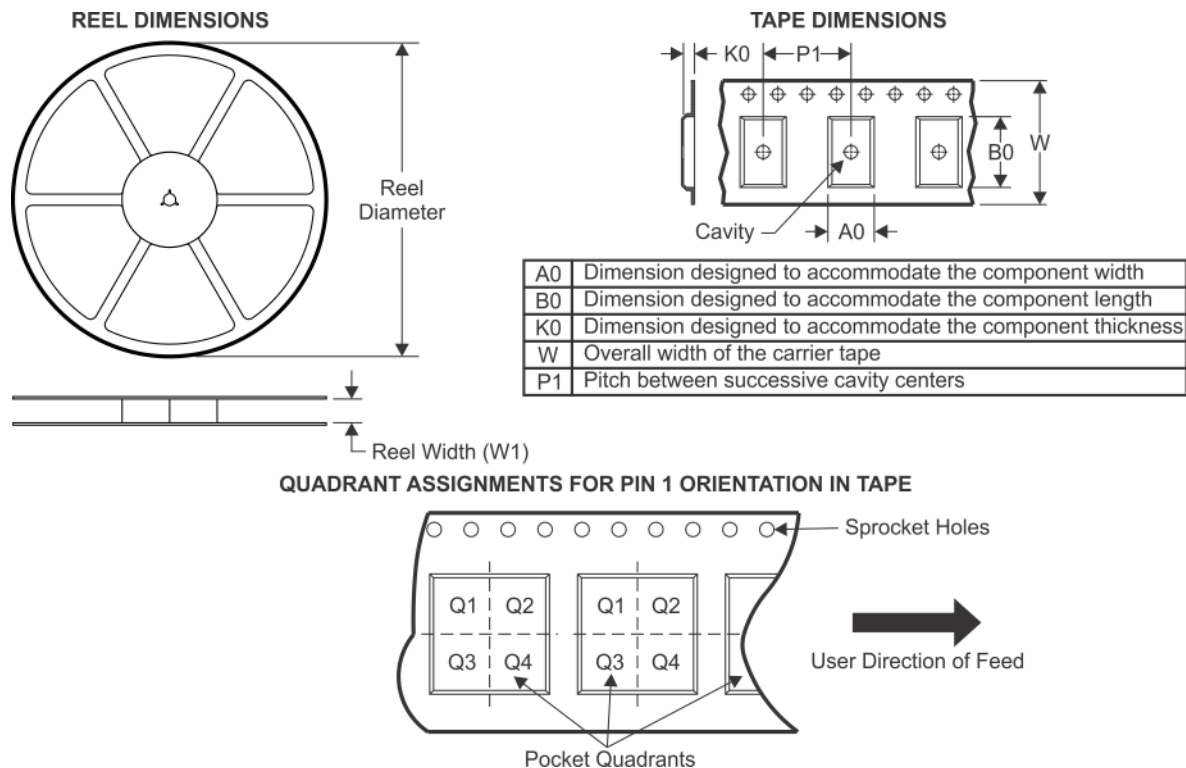
(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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**TAPE AND REEL INFORMATION**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
OPA397DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
OPA397DBVT	SOT-23	DBV	5	250	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
OPA397DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
OPA397DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0

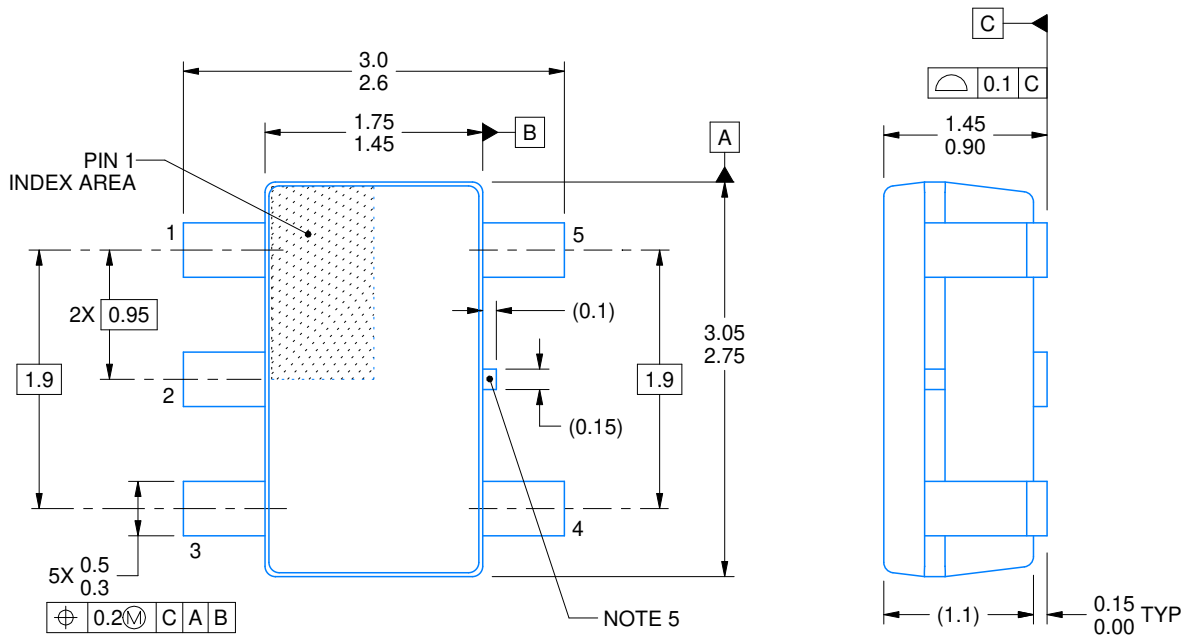
DBV0005A



# PACKAGE OUTLINE

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



4214839/G 03/2023

## NOTES:

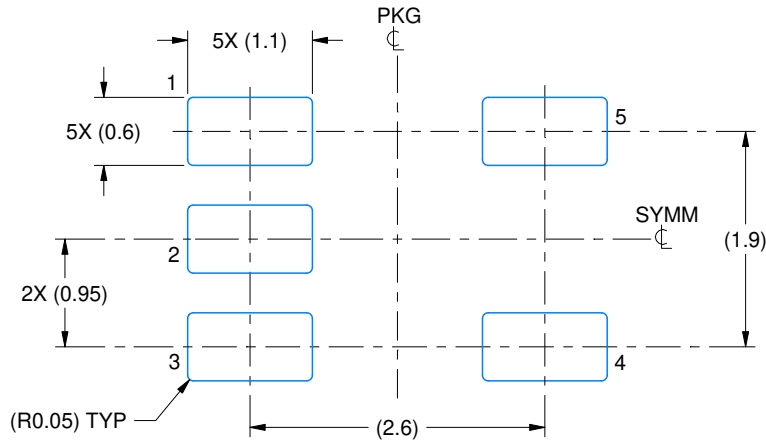
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-178.
4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
5. Support pin may differ or may not be present.

# EXAMPLE BOARD LAYOUT

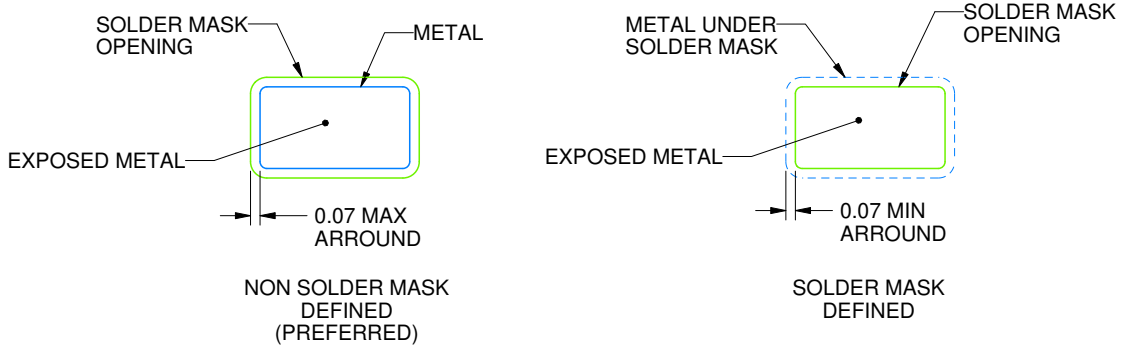
DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:15X



SOLDER MASK DETAILS

4214839/G 03/2023

NOTES: (continued)

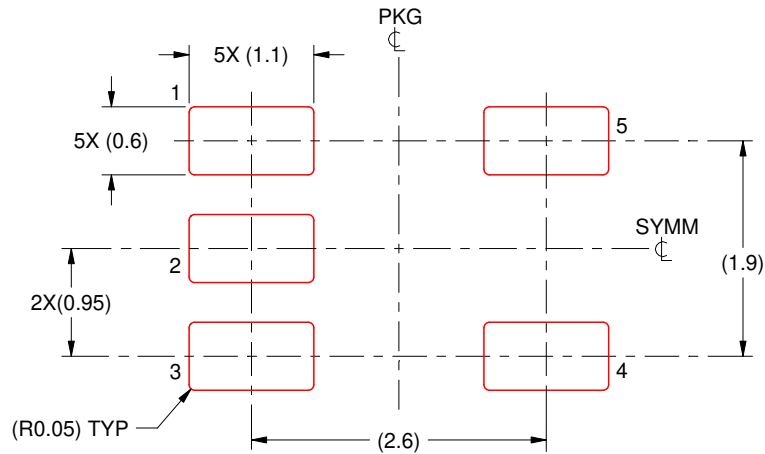
- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:15X

4214839/G 03/2023

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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